



#### **Product Highlights**

- PCIe<sup>®</sup> Gen 5.0, NVMe<sup>™</sup> 2.0d
- Sequential read/write speeds up to 14,900/14,100 MB/s<sup>2</sup> (2,048GB and 4,096GB¹ models)
- Random read/write speeds up to 2.3/2.4M IOPS<sup>2</sup> (2,048GB and 4,096GB<sup>1</sup> models)
- 512GB, 1,024GB, 2,048GB, and 4,096GB<sup>1</sup>
- M.2 2280
- SANDISK® TLC 3D NAND
- SANDISK® nCache™ 4.0 Technology
- Up to 2,400 TBW<sup>4</sup> Endurance (4,096GB<sup>1</sup> model)
- Optional TCG Opal v2.02

# (→) SANDISK® PC SN8050S NVMe<sup>™</sup> SSD

# Power, Performance, Efficiency: Redefined

The SANDISK® PC SN8050S NVMe™ SSD with PCle® Gen 5.0 and next generation SANDISK® TLC 3D NAND technology delivers leading-edge performance of up to 14,900/14,100 MB/s² sequential read/write speeds and up to 2.3/2.4M IOPS² random read/write speeds (2,048GB and 4,096GB¹ models) for demanding workloads including 8K video, fast loading of AI models, AI or business analytics, and scientific applications involving large datasets. With increased power efficiency providing 80% better MBps/Watt than the prior generation,¹² the SANDISK® PC SN8050S NVMe™ SSD can be integrated into-mobile workstations, desktops and laptops. The SANDISK® PC SN8050S NVMe™ SSD is available in capacities of 512GB to up to 4,096GB.¹ Optional TCG Opal v.2.02 data-at-rest encryption enhances data security.

#### A leading-edge PCIe<sup>®</sup> Gen 5.0 performance drive

Harness the speed of PCIe $^{\text{\tiny (8)}}$  Gen 5.0 with up to 14,900/14,100 MB/s $^{\text{\tiny (2)}}$  sequential read/write speeds and up to 2.3/2.4M IOPS $^{\text{\tiny (2)}}$  random read/write speeds (2,048GB and 4,096GB $^{\text{\tiny (1)}}$  models) for demanding workloads including 8K video, fast loading of AI models, demanding AI or business analytics, and scientific applications involving large datasets.

#### **Exceptional power efficiency**

With increased power efficiency providing 80% better MBps/Watt than prior generation,¹² the SANDISK® PC SN8050S NVMe™ SSD can be integrated into mobile workstations, desktops and laptops.

#### Massive storage for massive workloads

With capacities of 512GB to up to 4,096GB,1 store application with massive datasets, large AI LLMs (large language models), or 8K video libraries without worry.

#### Engineered for your workflow

Equipped with the next generation SANDISK® TLC 3D NAND delivering speed and reliability with up to 2,400 TBW $^4$  (4,096GB $^1$  model), the SANDISK® PC SN8050S NVMe $^{\text{TM}}$  SSD is engineered for write-intensive workloads like video editing, ensuring long-lasting performance and reliability.

#### **Data-at-rest encryption**

Industry standard TCG Opal v.2.02 encrypts data-at-rest to help with enhanced security and compliance.

### Multitask with multiple apps

With the latest NVMe™ 2.0d and SANDISK® nCache™ 4.0 technologies, seamlessly multitask between projects and fast burst writes for large file copies.



## **Specifications**

	512GB1	1,024GB <sup>1</sup>	2,048GB <sup>1</sup>	4,096GB <sup>1</sup>				
Product Specifications								
Interface		PCIe® Gen 5.0 x	4, NVMe™ 2.0d					
Form Factor	M.2 2280-S3-M							
DRAM NAND Type	SANDISK® TLC 3D NAND							
DRAM	Yes							
Performance <sup>2</sup>								
Sequential Read, 1MiB (MB/s), up to	14,100	14,100	14,900	14,900				
Sequential Write, 1MiB (MB/s), up to	10,600	13,200	14,100	14,100				
Random Read, 4KiB (IOPS), up to	1,200K	2,100K	2,300K	2,300K				
Random Write, 4KiB (IOPS), up to	2,300K	2,400K	2,400K	2,400K				
Power⁵								
Peak Power (W)	9.4	9.7	8.9	10.5				
Average Read (W)	9.1	9.2	6.5	7.4				
Average Write (W)	7.5	9.2	7.2	9.0				
Idle (Sleep, D3Hot) (mW)	3							
Reliability								
Endurance (TBW) <sup>4</sup>	300	600	1,200	2,400				
MTTF <sup>6</sup> (hours)	1.75 M							
Limited Warranty <sup>10</sup>	5 years							
Security								
Non-SED	TCG Pyrite 2.01 and ATA Security passthrough over NVMe™							
SED		TCG Opal 2.02 and ATA Secu	rity passthrough over NVMe™					
Regulatory								
RoHS Compliant <sup>7</sup>	Yes							
Certifications	FCC, UL, CE, CB-Scheme and Canada (ICES-003 (B)) TÜV, KCC, BSMI, VCCI, RCM, UKCA and Morocco							
Environmental								
Operating Temperature <sup>8</sup>	32°F to 185°F (0°C to 85°C)							
Non-Operating Temperature <sup>9</sup>	-40°F to 185°F (-40°C to +85°C)							
Operating Vibration	5 gRMS, 10 to 2,000Hz. 3 axes							
Non-Operating Vibration	4.9 gRMS, 7 to 800Hz. 3 axes							
Shock	1,500G @ 0.5 ms half-sine							
Physical Dimensions <sup>11</sup>								
Length	80mm							
Width	22mm							
Height	2.38mm							
Weight	7.1g							

#### **Ordering Information**

Form Factor	Security	512GB <sup>1</sup>	1,024GB1	2,048GB1	4,096GB1
M.2 2280	Non-SED	SDFPNJK-512G	SDFPNJK-1T00	SDFPNJL-2T00	SDFPNJL-4T00
M.2 2280	SED	SDFQNJK-512G	SDFQNJK-1T00	SDFQNJL-2T00	SDFQNJL-4T00

- 1GB = 1 billion bytes. Actual user capacity may be less depending on operating environment.
- Based on read speed, unless otherwise stated. 1 MB/s = 1 million bytes per second. IOPS = input/output operations per second. Based on internal testing; performance may vary depending upon host device, usage conditions, drive capacity, and other factors.
- Backward compatible with PCIe® Gen5 x2, Gen4 x4, Gen4 x2, Gen3 x4, Gen3 x2, Gen3 x1, Gen2 x4, Gen2 x2, and Gen2 x1 TBW (terabytes written) values calculated using JEDEC client workload (JESD219) and vary by product capacity.
- Average Read/Write Active Power is measured using a sustained sequential read and write operation (measured separately) and represents a moving average over a 1 second period. Peak power is the maximum instantaneous power measured while continuously processing sequential read and write commands (tested separately) and represents a maximum instantaneous power over a 10us period. Power may vary depending on test setup, configuration and firmware version.
- MTTF = Mean Time To Failure based on a sample population and internal testing using Telcordia™ stress part testing (Telcordia SR-332, GB, 25°C). MTTF is based on a sample population and is estimated by statistical measurements and acceleration algorithms. MTTF does not predict an individual drive's reliability and does not constitute a warranty.
- This drive is in compliance with the European Union Directive 2011/65/EU and Directive (EU) 2015/863 on the restriction of the use of certain hazardous substances (RoHS) in electrical and electronic equipment.

  Operational temperature is defined as temperature reported by the drive. Note that drive temperature readings are expected to be higher than ambient temperature when the SSD is placed inside a system. The SSD
- box package is rated up to 60°C.

  Non-operational storage temperature does not guarantee data retention.
- 5 years or Max Endurance (TBW) limit, whichever occurs first. See sandisk.com/support for regional specific warranty details. Physical product dimensions for length and width may vary by  $\pm$  0.10mm and product weight may vary by  $\pm$  10%.
- Compared with the PC SN8000S SSD 2,048GB model.

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